

<b>Notice of References Cited</b>			Application/Control No.	Applicant(s)/Patent Under Reexamination HIRANO ET AL.	
			Examiner George A. Goudreau	Art Unit 1763	Page 1 of 1

**U.S. PATENT DOCUMENTS**

*		Document Number Country Code-Number-Kind Code	Date MM-YYYY	Name	Classification
*	A	US-6,712,077	03-2004	Hirano et al.	134/1.3
*	B	US-6,355,536	03-2002	Figura et al.	438/398
*	C	US-6,368,913	04-2002	Yamamoto, Ichiro	438/255
*	D	US-6,413,833	07-2002	Yamamoto, Ichiro	438/398
	E	US-			
	F	US-			
	G	US-			
	H	US-			
	I	US-			
	J	US-			
	K	US-			
	L	US-			
	M	US-			

**FOREIGN PATENT DOCUMENTS**

*		Document Number Country Code-Number-Kind Code	Date MM-YYYY	Country	Name	Classification
*	N	JP 11-238,863	08-1999	Japan	Sonh	_____
*	O	JP 11-097,641	04-1999	Japan	Tadayuki	_____
*	P	JP 09-036,320	02-1997	Japan	Yamate	_____
	Q					
	R					
	S					
	T					

**NON-PATENT DOCUMENTS**

*		Include as applicable: Author, Title Date, Publisher, Edition or Volume, Pertinent Pages)
*	U	"A New Cylindrical Capacitor Using Hemispherical Grained Si (HSG-Si) For 256 Mb DRAMS"; <input type="checkbox"/> International Electron Devices Meeting; Watanabe et. al.; 1992; pp. 259-262
	V	
	W	
	X	

\*A copy of this reference is not being furnished with this Office action. (See MPEP § 707.05(a).)  
Dates in MM-YYYY format are publication dates. Classifications may be US or foreign.